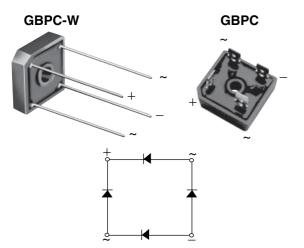


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Glass Passivated Single-Phase Bridge Rectifier



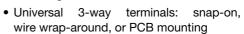
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	12 A, 15 A, 25 A, 35 A							
V _{RRM}	50 V to 1000 V							
I _{FSM}	200 A, 300 A, 300 A, 400 A							
I _R	5 μΑ							
V _F at I _F	1.1 V							
T _J max.	150 °C							
Package	GBPC, GBPC-W							
Circuit configuration	Quad							

FEATURES

• UL recognition file number E54214





- Typical I_R less than 0.3 μA
- · High surge current capability
- · Low thermal resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for power supply, home appliances, office equipment, industrial automation applications.

MECHANICAL DATA

Case: GBPC, GBPC-W

Molding compound meets UL 94 V-0 flammability rating Base P/N-E4 - RoHS-compliant, commercial grade

Terminals: Nickel plated on faston lugs or silver plated on wire leads, solderable per J-STD-002 and JESD 22-B102. Suffix letter "W" added to indicate wire leads (e.g. GBPC12005W).

Polarity: As marked, positive lead by beveled corner

Mounting Torque: 20 inches-lbs. max.

PARAMETER		SYMBOL	GBPC12, 15, 25, 35							
			005	01	02	04	06	08	10	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage		V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage		V_{DC}	50	100	200	400	600	800	1000	V
	GBPC12		12							
Maximum average forward rectified	GBPC15	I _{F (AV)}	15							
output current (Fig. 1)	GBPC25		25							A
	GBPC35		35							İ
	GBPC12		200							
Peak forward surge current single	GBPC15		300							
sine-wave superimposed on rated load	GBPC25	I _{FSM}	300							
	GBPC35		400							1
	GBPC12		160							
Rating (non-repetitive, for t greater than	GBPC15	l ² t	375							
1 ms and less than 8.3 ms) for fusing	GBPC25	I-t	375							A ² s
GBPC			660							
RMS isolation voltage from case to leads		V _{ISO}	2500							V
Operating junction storage temperature range		T _J , T _{STG}	-55 to +150							°C



GBPC12, GBPC15, GBPC25, GBPC35

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)											
PARAMETER		TEST CONDITIONS	SYMBOL			LINUT					
			STWIBUL	005	01	02	04	06	08	10	UNIT
	GBPC12	I _F = 6.0 A									
Maximum instantaneous forward drop per diode	GBPC15	I _F = 7.5 A	V _F	4.4							V
	GBPC25	I _F = 12.5 A		1.1						V	
	GBPC35	I _F = 17.5 A									
Maximum reverse DC current at rated		T _A = 25 °C		5.0							
DC blocking voltage per diode		T _A = 125 °C	I _R	500							μA
Typical junction capacitano	e per diode	4 V, 1 MHz	CJ	160				pF			

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	GBPC12, 15, 25, 35							UNIT	
PARAMETER		STIVIBUL	005	01	02	04	06	08	10	UNIT
GBPC12 to GBPC25		R _{eJC} ⁽¹⁾	1.9							°C/W
Typical thermal resistance	GBPC35	H _B JC (.)	1.4							C/VV

Notes

⁽²⁾ Bolt down on heatsink with silicone thermal compound between bridge and mounting surface for maximum heat transfer with #10 screw

ORDERING INFORMATION (Example)									
PREFERRED P/N	N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTI		BASE QUANTITY	DELIVERY MODE					
GBPC1206-E4/51	15.79	51	100	Paper box					
GBPC1506-E4/51	15.79	51	100	Paper box					
GBPC2506-E4/51	15.79	51	100	Paper box					
GBPC3506-E4/51	15.79	51	100	Paper box					
GBPC1206W-E4/51	13.8	51	100	Paper box					
GBPC1506W-E4/51	13.8	51	100	Paper box					
GBPC2506W-E4/51	13.8	51	100	Paper box					
GBPC3506W-E4/51	13.8	51	100	Paper box					

⁽¹⁾ With heatsink

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

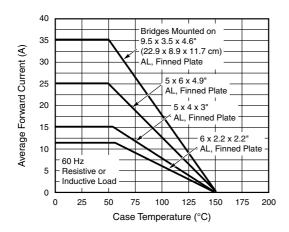


Fig. 1 - Maximum Output Rectified Current

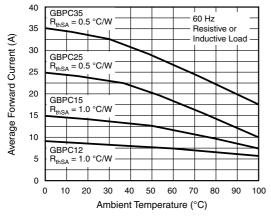


Fig. 2 - Maximum Output Rectified Current

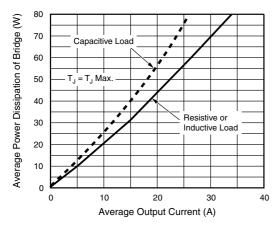


Fig. 3 - Maximum Power Dissipation

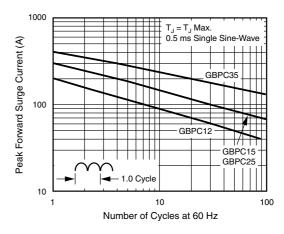


Fig. 4 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

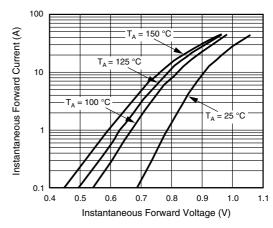


Fig. 5 - Typical Instantaneous Forward Characteristics Per Diode

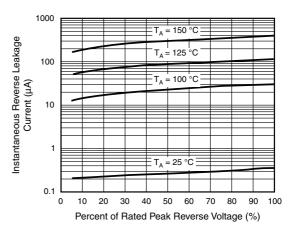


Fig. 6 - Typical Reverse Leakage Characteristics Per Diode





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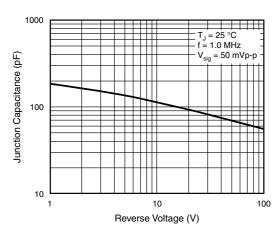


Fig. 7 - Typical Junction Capacitance Per Diode

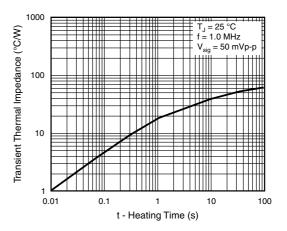
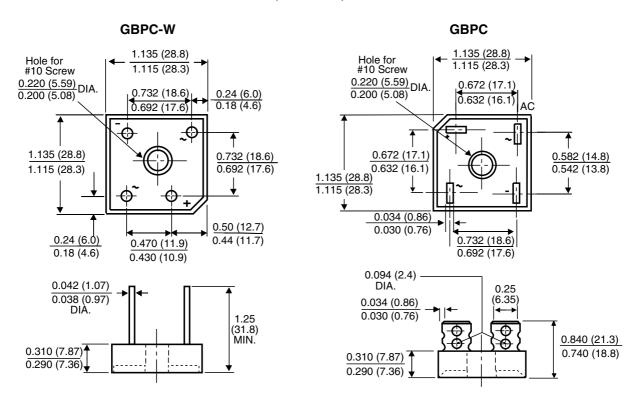


Fig. 8 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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